

1.Base 2.Collector 3.Emitter

# NPN Triple Diffused Planar Silicon Transistor

#### Absolute Maximum Ratings $T_{C}=25^{\circ}C$ unless otherwise noted Symbol Parameter Rating Units $V_{CBO}$ Collector-Base Voltage 1500 V ٧ $V_{CEO}$ Collector-Emitter Voltage 750 V V<sub>EBO</sub> Emitter-Base Voltage 6 Collector Current (DC) 10 А $I_{C}$ Collector Current (Pulse) 20 А I<sub>CP</sub>\* $\mathsf{P}_\mathsf{C}$ **Collector Dissipation** 60 W 150 °C $\mathsf{T}_\mathsf{J}$ Junction Temperature T<sub>STG</sub> Storage Temperature -55 ~ 150 °C

\* Pulse Test: Pulse Width=5ms, Duty Cycle < 10%

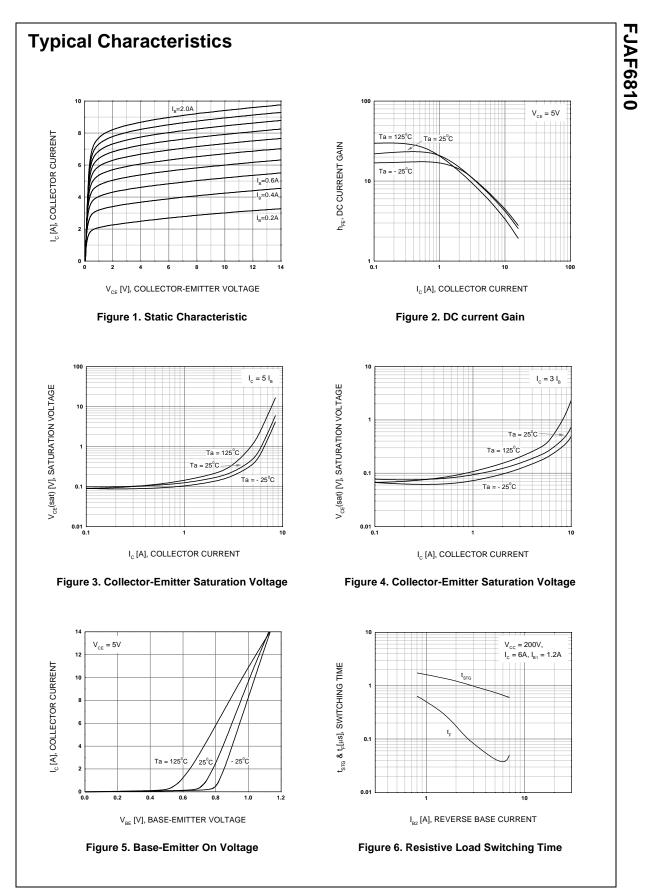
## Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
I <sub>CES</sub>	Collector Cut-off Current	V <sub>CB</sub> =1400V, R <sub>BE</sub> =0			1	mA
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =800V, I <sub>E</sub> =0			10	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB}=4V, I_{C}=0$			1	mA
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =500μA, I <sub>C</sub> =0	6			V
h <sub>FE1</sub> h <sub>FE2</sub>	DC Current Gain	V <sub>CE</sub> =5V, I <sub>C</sub> =1A V <sub>CE</sub> =5V, I <sub>C</sub> =6A	10 5		8	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =6A, I <sub>B</sub> =1.5A			3	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> =6A, I <sub>B</sub> =1.5A			1.5	V
t <sub>STG</sub> *	Storage Time	$V_{CC}$ =200V, $I_{C}$ =6A, $R_{L}$ =33 $\Omega$			3	μs
t <sub>F</sub> *	Fall Time	I <sub>B1</sub> =1.2A, I <sub>B2</sub> = - 2.4A			0.2	μs

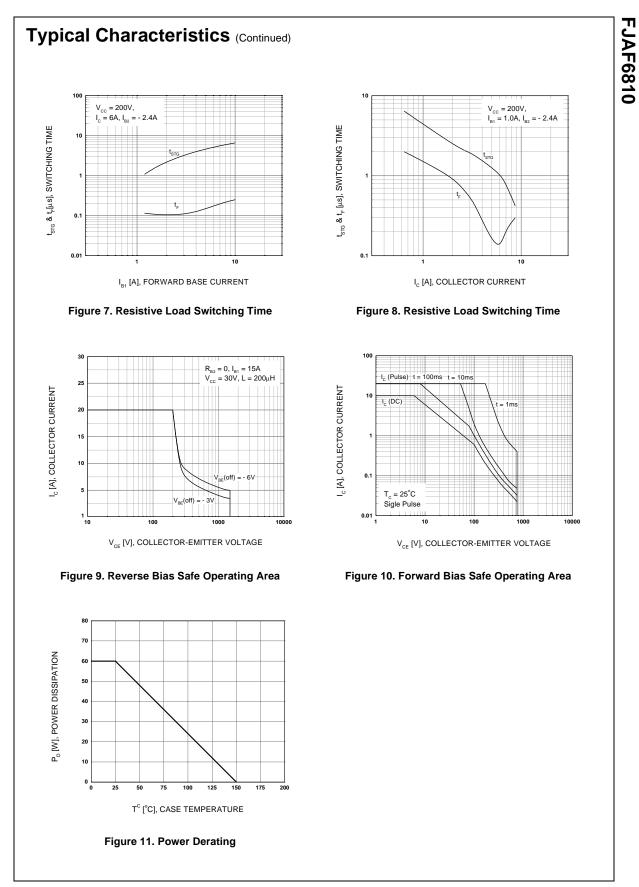
\* Pulse Test: PW=20 $\mu$ s, duty Cycle=1% Pulsed

### Thermal Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Тур	Max	Units
R <sub>θjC</sub>	Thermal Resistance, Junction to Case		2.08	°C/W

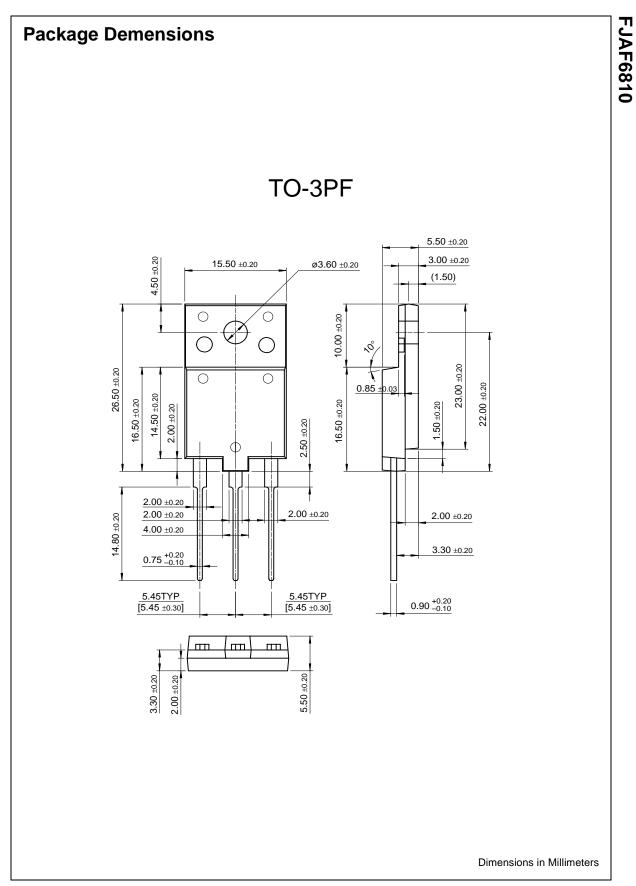


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